



IEPE low-frequency measurement-type acceleration sensor





PRODUCTS FEATURES

- Selected ultra-low frequency built-in integrated circuits
- Specially designed for low frequency test and measurement
- Memory alloy fasteners, shear structure, stable and reliable
- Multiple output and mounting options
- Top M5 connector output

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1. Performance parameters for SSA-P4LF1S1:

Table 1. Characteristics for SSA-P4LF1S1

	Table 1. Characteristics for GGA-1		
Parameters	Value	Units	
Sensitivity	100	mV/g	
Measurement Range	±50	g	
Frequency response ±5%	0.1~6000	Hz	
Frequency response ±10%	0.05~7000	Hz	
Magnitude linearity	≤1	%	
Lateral Sensitivity	≤5	%	
Installation of resonant frequency	≥25	kHz	
Time constants	≤1	s	
Resolution	0.001	grms	
Base strain	0.0008	g/ε	
Hitting the Limits ¹	1000	gpK	
Maximum vibration ²	400	grms	
Sensitivity temperature coefficient	-0.01	%/°C	
Operating temperature	-40~120	°C	
Constant voltage supply	20~30	VDC	
Constant current supply	2~20	mA	
Full-scale voltage	±5	V	
Maximum over-range output	±6	V	
DC bias	8~12	V	
Output Impedance	≤100	Ω	
Sensitive components	PZT-5 Piezoelectric Ceramic		
Housing Material	Stainless Steel		
Seal form	Laser welding IP68		
Output connector	M5 Top		
Mounting form	M5		
Quality	24	g	
Recommended mounting torque	3.0	N*m	
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Note: 1,2: refers to the sensor in the non-energized state, the mechanical structure is not damaged, and not the working state.

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2. Performance parameters for SSA-P4LF1S2:

Table 2. Characteristics for SSA-P4LF1S2

Parameters	Value	Units
Sensitivity	1000	mV/g
Measurement Range	±5	g
Frequency response ±5%	0.06~1000	Hz
Frequency response ±10%	0.04~1500	Hz
Magnitude linearity	≤1	%
Lateral Sensitivity	_ · ≤5	%
Installation of resonant frequency	≥8	kHz
Time constants	≥10	S
Resolution	0.00001	grms
Base strain	0.0008	g/ε
Hitting the Limits ¹	100	gpK
Maximum vibration ²	50	grms
Sensitivity temperature coefficient	-0.1	%/°C
	-40~120	% C
Operating temperature	20~30	VDC
Constant voltage supply		1 - 5
Constant current supply	2~20	mA
Full-scale voltage	±5	V
Maximum over-range output	±6	V
DC bias	8~12	V
Output Impedance	≤100	Ω
Sensitive components	PZT-5 Piezoelectric Ceramic	
Housing Material	Stainless Steel	
Seal form	Laser welding IP68	
Output connector	M5 Top	
Mounting form	M5	
Quality	60	g
Recommended mounting torque	3.0	N*m

Note: 1,2: refers to the sensor in the non-energized state, the mechanical structure is not damaged, and not the working state.

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3. Performance parameters for SSA-P4LF1S3:

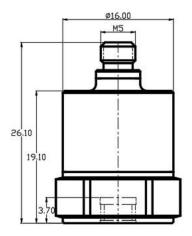
Table 3. Characteristics for SSA-P4LF1S3

	Table 5. Characteristics for GGA-1 4EF		
Parameters	Value	Units	
Sensitivity	1000	mV/g	
Measurement Range	±5	g	
Frequency response ±5%	0.06~2000	Hz	
Frequency response ±10%	0.04~3000	Hz	
Magnitude linearity	≤1	%	
Lateral Sensitivity	≤5	%	
Installation of resonant frequency	≥13	kHz	
Time constants	≥10	S	
Resolution	0.00001	grms	
Base strain	0.005	g/ε	
Hitting the Limits ¹	100	gpK	
Maximum vibration ²	40	grms	
Sensitivity temperature coefficient	-0.1	%/°C	
Operating temperature	-40~120	°C	
Constant voltage supply	20~30	VDC	
Constant current supply	2~20	mA	
Full-scale voltage	±5	V	
Maximum over-range output	±6	V	
DC bias	8~12	V	
Output Impedance	≤100	Ω	
Sensitive components	PZT-5 Piezoelectric Ceramic		
Housing Material	Stainless Steel		
Seal form	Laser welding IP68		
Output connector	М5 Тор		
Mounting form	M5		
Quality	60	g	
Recommended mounting torque	3.0	N*m	

Note: 1,2: refers to the sensor in the non-energized state, the mechanical structure is not damaged, and not the working state.

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4. Mechanical dimensions



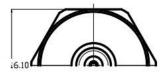
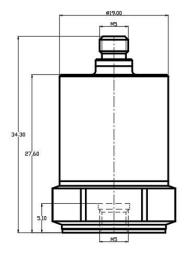


Figure 4.1. Mechanical dimensions for SSA-P4LF1S1



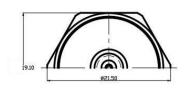


Figure 4.2. Mechanical dimensions for SSA-P4LF1S2/3



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Development, production and supply of high-tech sensors